Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low leakage current
- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.0 × 0.6 × 0.37 mm
- ElectroStatic Discharge (ESD) protection > 1 kV HBM
- Drain-source on-state resistance R_{DSon} = 1.02 Ω

3. Applications

- Relay driver
- · High-speed line driver
- · High-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V	
V_{GS}	gate-source voltage			-8	-	8	V	
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-500	mA	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I_D = -500 mA; T_j = 25 °C		-	1.02	1.4	Ω	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1 🗀	D
2	S	source		
3	D	drain	Transparent top view DFN1006B-3 (SOT883B)	G S S 017aaa259

6. Ordering information

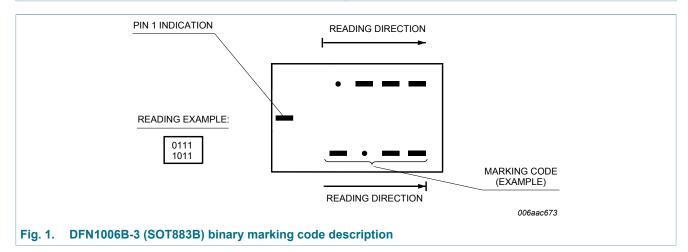
Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMZB950UPEL	DFN1006B-3	DFN1006B-3: leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMZB950UPEL	0101 1111



2 / 15

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V_{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-500	mA
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-300	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-2	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	360	mW
			[1]	-	715	mW
		T _{sp} = 25 °C		-	2700	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	n diode		'	'	•	
Is	source current	T _{amb} = 25 °C	[1]	-	-350	mA

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

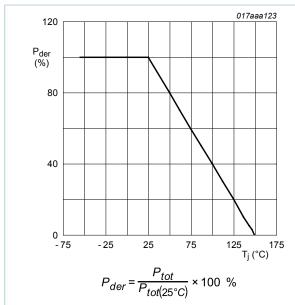


Fig. 2. Normalized total power dissipation as a function of junction temperature

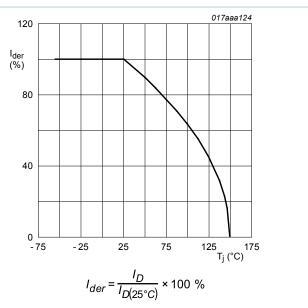
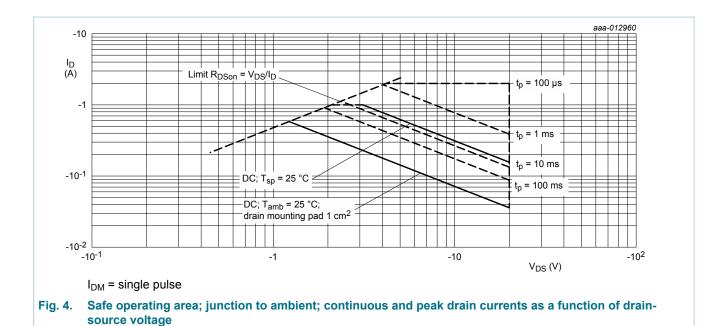


Fig. 3. Normalized continuous drain current as a function of junction temperature

20 V, P-channel Trench MOSFET



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	305	360	K/W
			[2]	-	150	175	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	40	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

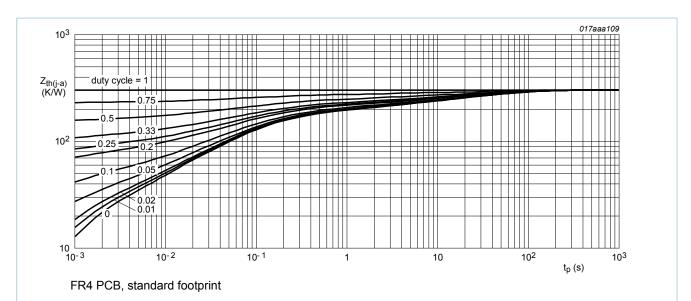


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

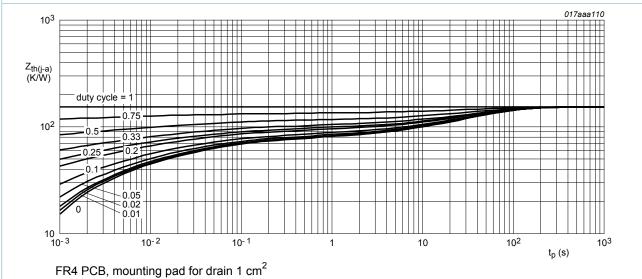


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

tatic characteristics	•		Max	Unit
$(BR)DSS$ drain-source I_D = -250 μA; V_{GS} = 0 V; T_j = 25 °C breakdown voltage	-20	-	-	V
gate-source threshold I_D = -250 μ A; V_{DS} = V_{GS} ; T_j = 25 °C voltage	-0.45	-0.7	-0.95	V
drain leakage current $V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-1	μΑ
$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	-10	μΑ
$V_{DS} = -5 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-25	nA
gate leakage current $V_{GS} = 8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	10	μΑ
$V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-10	μΑ
$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-1	μΑ
$V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	1	μΑ
$V_{GS} = 1.8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	50	nA
$V_{GS} = -1.8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	-50	nA
drain-source on-state $V_{GS} = -4.5 \text{ V}; I_D = -500 \text{ mA}; T_j = 25 \text{ °C}$	-	1.02	1.4	Ω
resistance $V_{GS} = -4.5 \text{ V; } I_D = -500 \text{ mA; } T_j = 150 \text{ °C}$	-	1.54	2.1	Ω
$V_{GS} = -2.5 \text{ V}; I_D = -200 \text{ mA}; T_j = 25 \text{ °C}$	-	1.27	2.2	Ω
$V_{GS} = -1.8 \text{ V}; I_D = -40 \text{ mA}; T_j = 25 ^{\circ}\text{C}$	-	1.7	3.3	Ω
$V_{GS} = -1.5 \text{ V}; I_D = -10 \text{ mA}; T_j = 25 ^{\circ}\text{C}$	-	2.3	5	Ω
$V_{GS} = -1.2 \text{ V}; I_D = -1 \text{ mA}; T_j = 25 \text{ °C}$	-	3.5	-	Ω
forward V_{DS} = -10 V; I_{D} = -500 mA; T_{j} = 25 °C transconductance	-	480	-	mS
ynamic characteristics	·			
$V_{DS} = -10 \text{ V}; I_D = -450 \text{ mA};$	-	1.19	2.1	nC
V_{GS} gate-source charge $V_{GS} = -4.5 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	0.17	-	nC
gate-drain charge	-	0.1	-	nC
input capacitance $V_{DS} = -10 \text{ V}$; $f = 1 \text{ MHz}$; $V_{GS} = 0 \text{ V}$;	-	43	-	pF
output capacitance $T_j = 25 ^{\circ}\text{C}$	-	14	-	pF
reverse transfer capacitance	-	8	-	pF
turn-on delay time $V_{DS} = -10 \text{ V}; I_D = -0.45 \text{ A}; R_L = 22 \Omega;$	-	2.3	-	ns
rise time V_{GS} = -4.5 V; $R_{G(ext)}$ = 6 Ω; T_j = 25 °C	-	5	-	ns
(off) turn-off delay time	-	13.5	-	ns
fall time	-	6	-	ns
ource-drain diode				,
source-drain voltage $I_S = -115 \text{ mA}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 ^{\circ}\text{C}$	-	-0.7	-1.2	V

6 / 15

20 V, P-channel Trench MOSFET

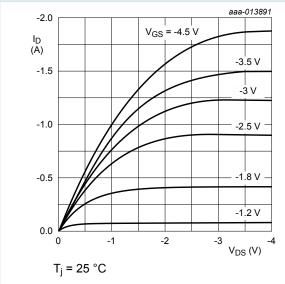


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

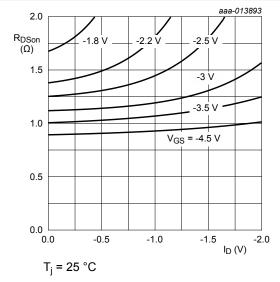


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

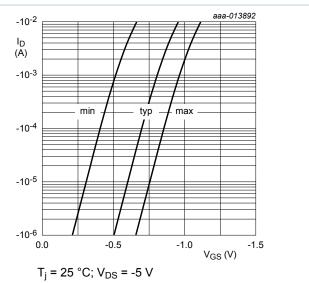


Fig. 8. Sub-threshold drain current as a function of gate-source voltage

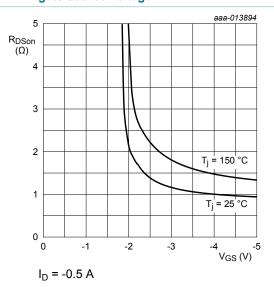


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

20 V, P-channel Trench MOSFET

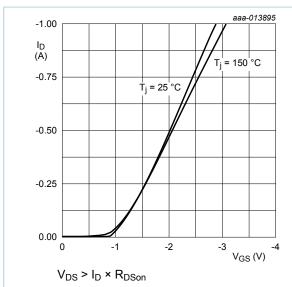


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

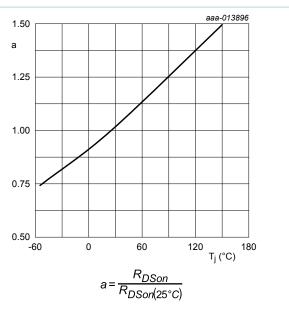


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

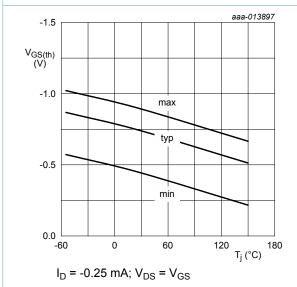


Fig. 13. Gate-source threshold voltage as a function of junction temperature

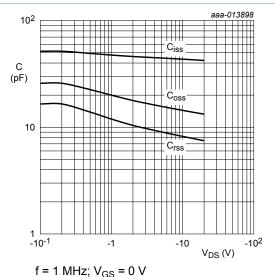


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

20 V, P-channel Trench MOSFET

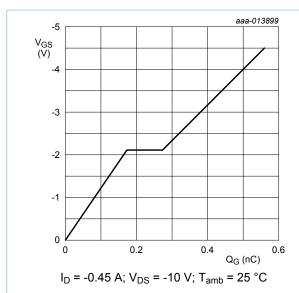


Fig. 15. Gate-source voltage as a function of gate charge; typical values

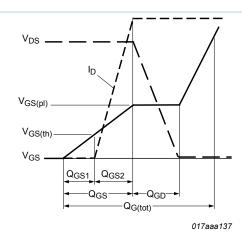


Fig. 16. MOSFET transistor: Gate charge waveform definitions

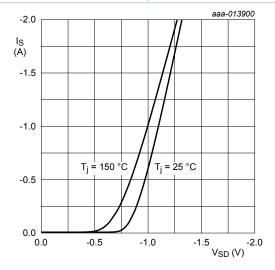
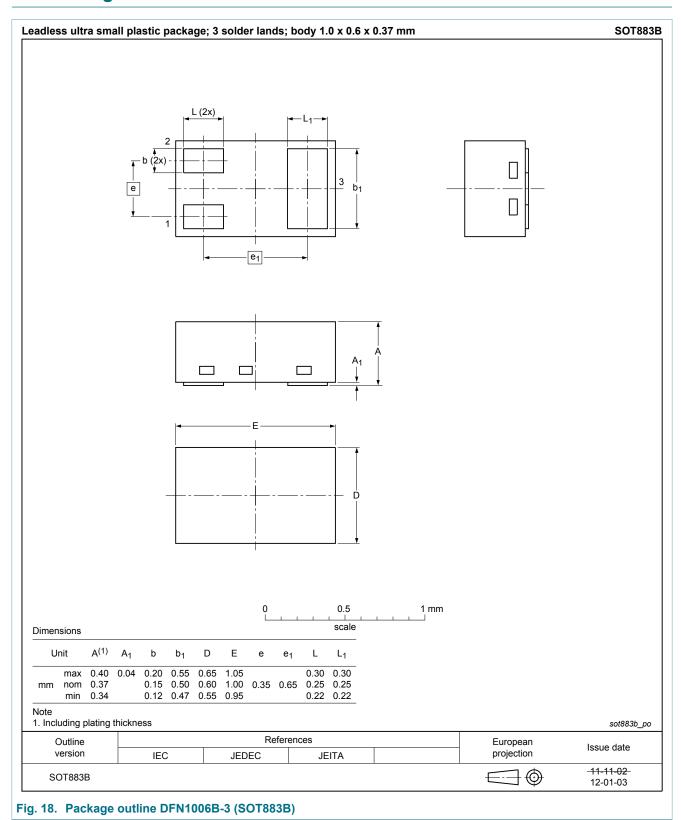


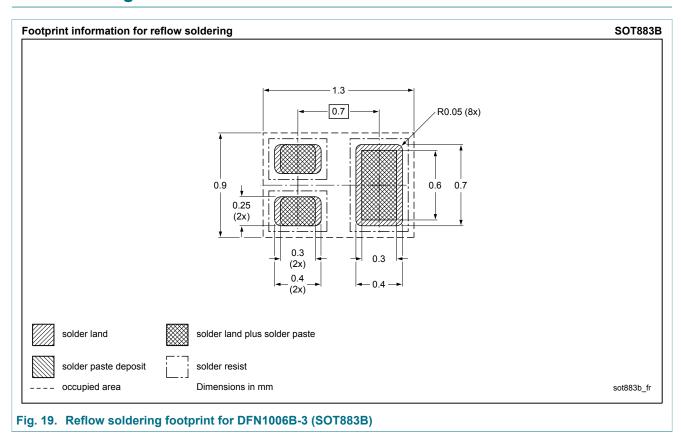
Fig. 17. Source current as a function of source-drain voltage; typical values

 $V_{GS} = 0 V$

11. Package outline



12. Soldering



13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMZB950UPEL v.1	20161205	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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15. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	. Characteristics	6
11.	. Package outline	10
12	. Soldering	11
13.	. Revision history	12
14.	. Legal information	13

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